DIGITRON™ Semiconductors

High-reliability discrete products
and engineering services since 1977

HER201G-HER208G

HIGH EFFICIENCY RECTIFIERS

FEATURES

- Available as “HR” (high reliability) screened per MIL-PRF-19500, JANTX level. Add “HR” suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding “-PBF” suffix.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T_A = 25°c unless otherwise noted)

Characteristics	Symbol	HER								Units
		201G	202G	203G	204G	205G	206G	207G	208G	
Maximum Forward Rectified Current T_A = 50°C	I_O	2.0								A
Maximum Forward Surge Current	I_{FSM}	60								A
Maximum Reverse Current $V_R = V_{RRM}$, T_J = 25°C $V_R = V_{RRM}$, T_J = 125°C	I_R	5.0 150								µA
Typical Junction Capacitance f = 1MHz and applied 4V DC Reverse Voltage	C_J	30								pF
Storage Temperature Range	T_{STG}	-65 to +175								°C
Operating Temperature Range	T_J	-55 to +150								°C
Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	V
Continuous Reverse Voltage	V_R	50	100	200	300	400	600	800	1000	V
Maximum Forward Voltage @ I_F = 1.5A	V_F	1.0	1.0	1.0	1.3	1.3	1.85	1.85	1.85	V
Maximum Reverse Recovery Time (1)	t_{rr}	50	50	50	50	50	75	75	75	ns

Note 1: Reverse recovery time test condition, I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A

DIGITRON™ Semiconductors

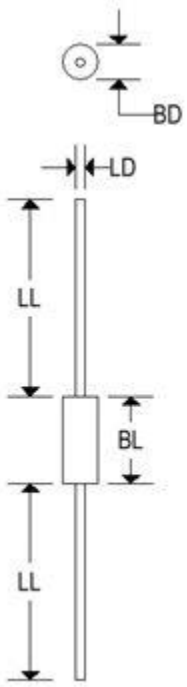
High-reliability discrete products
and engineering services since 1977

HER201G-HER208G

HIGH EFFICIENCY RECTIFIERS

MECHANICAL CHARACTERISTICS

Case:	DO-15
Marking:	Alpha-numeric
Polarity:	Cathode band



	DO-15			
	Inches		Millimeters	
	Min	Max	Min	Max
BD	0.100	0.140	2.540	3.556
BL	0.200	0.300	5.080	7.620
LD	0.028	0.032	0.711	0.813
LL	1.000	-	25.400	-

DIGITRON™ Semiconductors

High-reliability discrete products and engineering services since 1977

HER201G-HER208G

HIGH EFFICIENCY RECTIFIERS

FIG.1-TYPICAL FORWARD CHARACTERISTICS

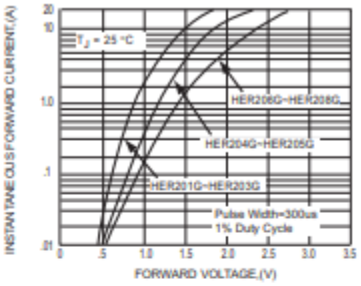


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

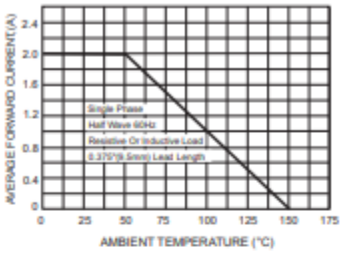
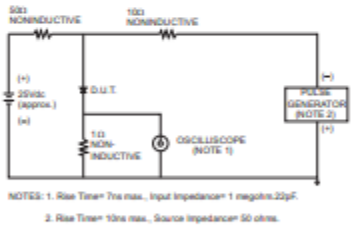


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm,22pF.

2. Rise Time= 10ns max., Source Impedance= 50 ohms.

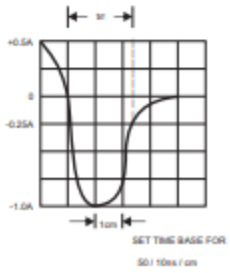


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

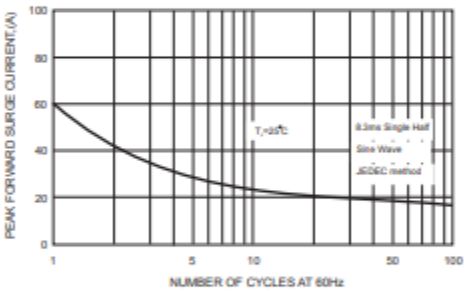


FIG.5-TYPICAL JUNCTION CAPACITANCE